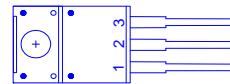
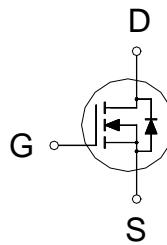


**NIKO-SEM****N-Channel High Voltage Mode  
Field Effect Transistor****P1560ZTF:TO-220F  
P1560ZTFS:TO-220FS  
Halogen-Free & Lead-Free****PRODUCT SUMMARY**

$V_{(BR)DSS}$	$R_{DS(ON)}$	$I_D$
600V	280mΩ	15A

**ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ C$  Unless Otherwise Noted)**

PARAMETERS/TEST CONDITIONS	SYMBOL	LIMITS	UNITS
Drain-Source Voltage	$V_{DS}$	600	V
Gate-Source Voltage	$V_{GS}$	$\pm 30$	V
Continuous Drain Current <sup>2</sup>	$I_D$	15	A
		9	
Pulsed Drain Current <sup>1</sup>	$I_{DM}$	40	
Avalanche Current <sup>3</sup>	$I_{AS}$	3.8	A
Avalanche Energy <sup>3</sup>	$E_{AS}$	289	mJ
Power Dissipation	$P_D$	43	W
		17	
Operating Junction & Storage Temperature Range	$T_j, T_{stg}$	-55 to 150	°C

**THERMAL RESISTANCE RATINGS**

THERMAL RESISTANCE	SYMBOL	TYPICAL	MAXIMUM	UNITS
Junction-to-Case	$R_{\theta JC}$		2.9	°C / W
Junction-to-Ambient	$R_{\theta JA}$		62.5	°C / W

<sup>1</sup>Pulse width limited by maximum junction temperature.<sup>2</sup>Ensure that the channel temperature does not exceed 150°C.<sup>3</sup> $V_{DD} = 50V$ ,  $L = 40mH$ , starting  $T_J = 25^\circ C$ .**ELECTRICAL CHARACTERISTICS ( $T_J = 25^\circ C$ , Unless Otherwise Noted)**

PARAMETER	SYMBOL	TEST CONDITIONS	LIMITS			UNIT
			MIN	TYP	MAX	
<b>STATIC</b>						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	600			V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	2	3.2	4	
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0V, V_{GS} = \pm 30V$			$\pm 100$	nA
Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 600V, V_{GS} = 0V, T_C = 25^\circ C$			1	$\mu A$
		$V_{DS} = 480V, V_{GS} = 0V, T_C = 100^\circ C$			100	

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Drain-Source On-State Resistance <sup>1</sup>	$R_{DS(ON)}$	$V_{GS} = 10V, I_D = 7.5A$	250	280	$m\Omega$
Forward Transconductance <sup>1</sup>	$g_{fs}$	$V_{DS} = 10V, I_D = 7.5A$	10		S
<b>DYNAMIC</b>					
Input Capacitance	$C_{iss}$	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$	1174		pF
Output Capacitance	$C_{oss}$		900		
Reverse Transfer Capacitance	$C_{rss}$		15		
Effective Output Capacitance <sup>4</sup>	$C_{o(er)}$		58		
Total Gate Charge <sup>2</sup>	$Q_g$	$V_{DD} = 480V, I_D = 7.5A, V_{GS} = 10V$	41		nC
Gate-Source Charge <sup>2</sup>	$Q_{gs}$		6		
Gate-Drain Charge <sup>2</sup>	$Q_{gd}$		21		
Turn-On Delay Time <sup>2</sup>	$t_{d(on)}$		35		
Rise Time <sup>2</sup>	$t_r$	$V_{DD} = 300V, I_D = 7.5A, R_G = 10\Omega$	70		nS
Turn-Off Delay Time <sup>2</sup>	$t_{d(off)}$		95		
Fall Time <sup>2</sup>	$t_f$		48		
<b>SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS (<math>T_J = 25^\circ C</math>)</b>					
Continuous Current <sup>3</sup>	$I_S$			15	A
Forward Voltage <sup>1</sup>	$V_{SD}$	$I_F = 7.5A, V_{GS} = 0V$		1.5	V
Reverse Recovery Time	$t_{rr}$	$I_F = 7.5A, dI_F/dt = 100A / \mu S$	290		nS
Reverse Recovery Charge	$Q_{rr}$		3.4		uC

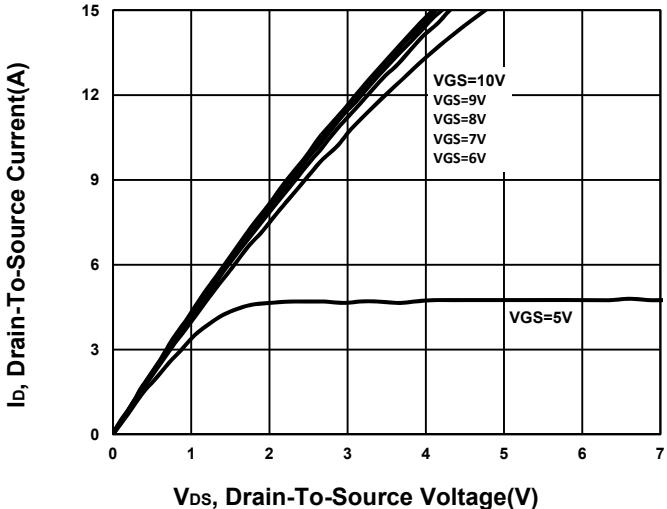
<sup>1</sup>Pulse test : Pulse Width  $\leq 380 \mu sec$ , Duty Cycle  $\leq 2\%$ .<sup>2</sup>Independent of operating temperature.<sup>3</sup>Pulse width limited by maximum junction temperature.<sup>4</sup> $C_{o(er)}$  is a fixed capacitance that gives the same stored energy as  $C_{oss}$  while  $V_{DS}$  is rising from 0 to 80%  $V_{(BR)DSS}$ .

**NIKO-SEM**

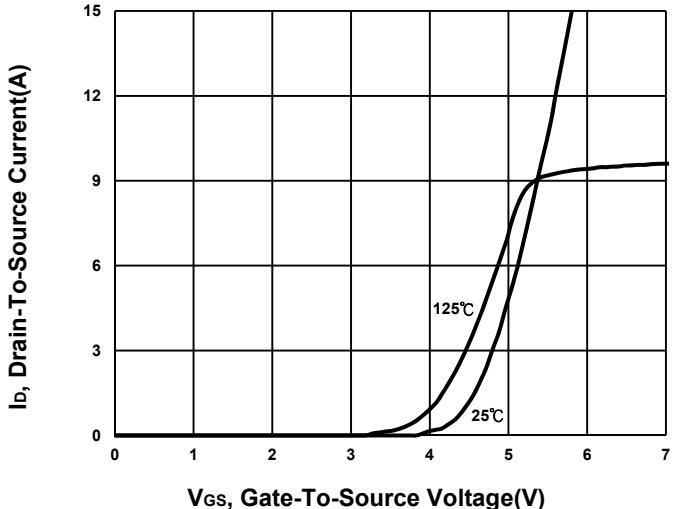
**N-Channel High Voltage Mode  
Field Effect Transistor**

**P1560ZTF:TO-220F  
P1560ZTFS:TO-220FS  
Halogen-Free & Lead-Free**

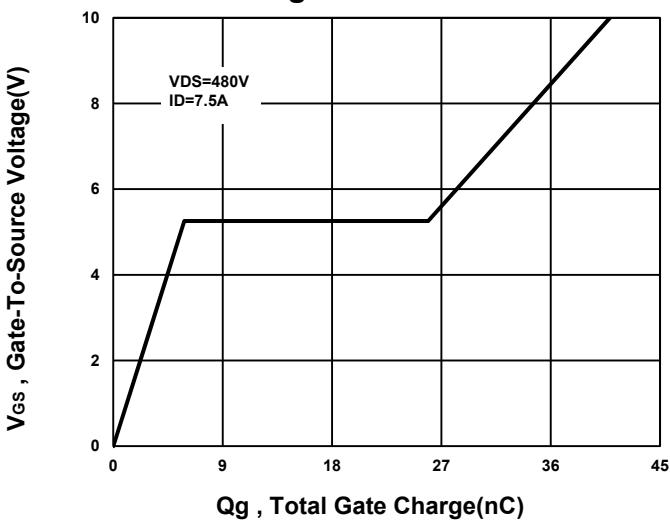
#### Output Characteristics



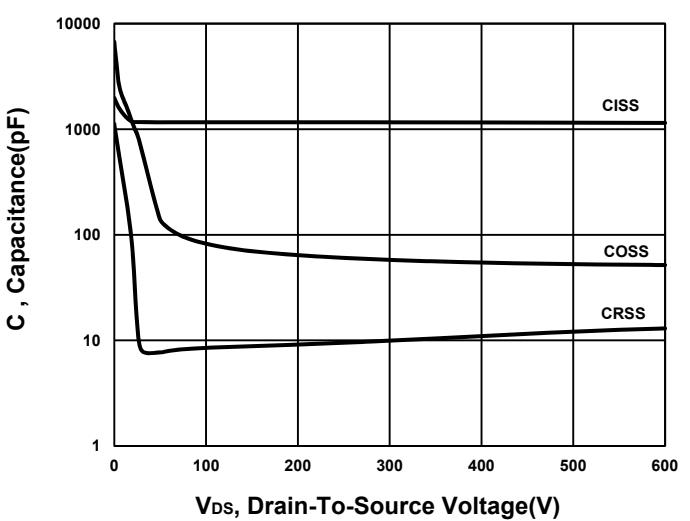
#### Transfer Characteristics



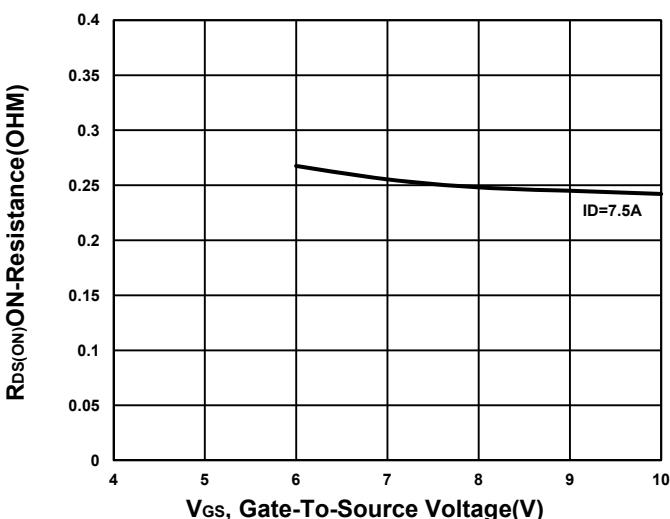
#### Gate charge Characteristics



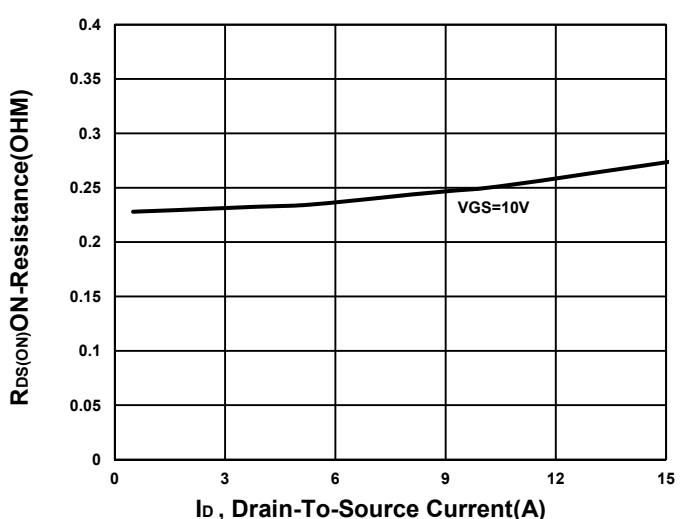
#### Capacitance Characteristic

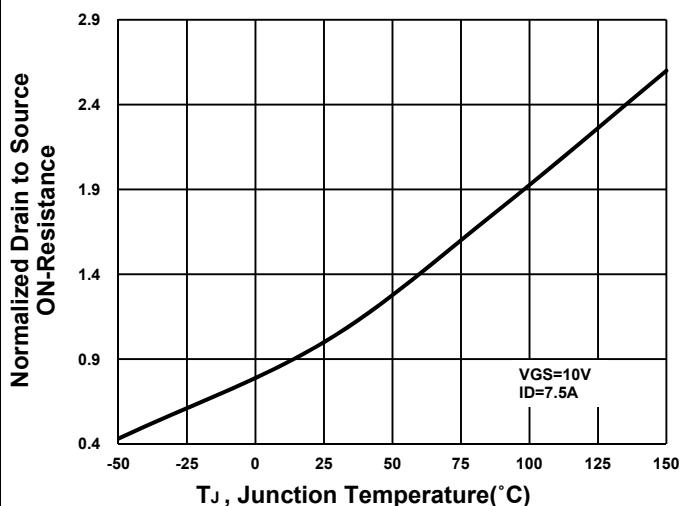
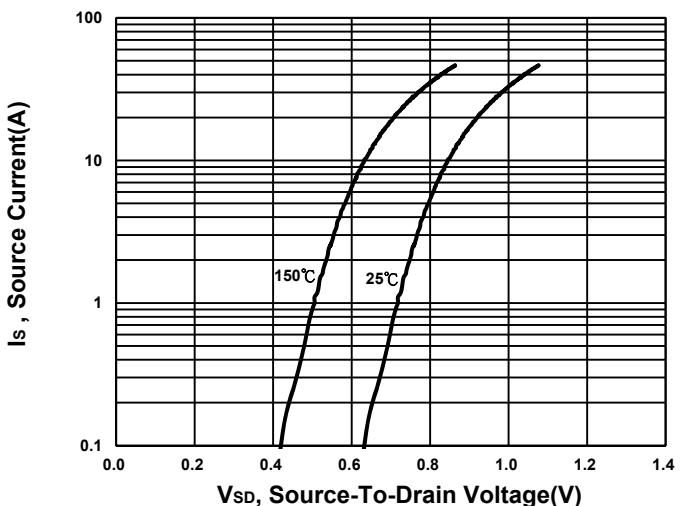
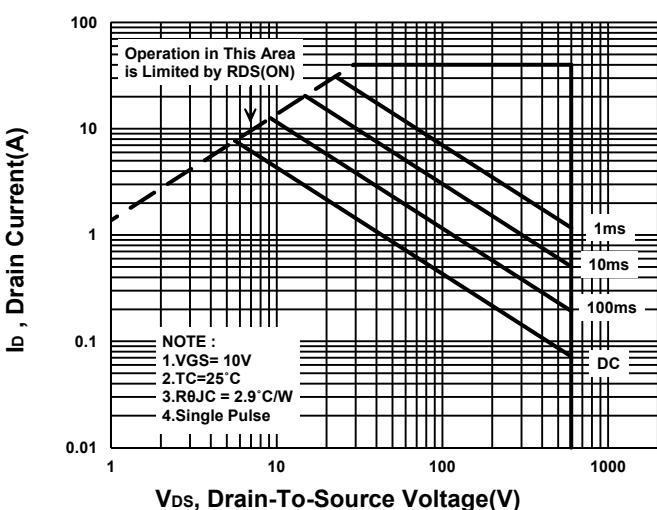
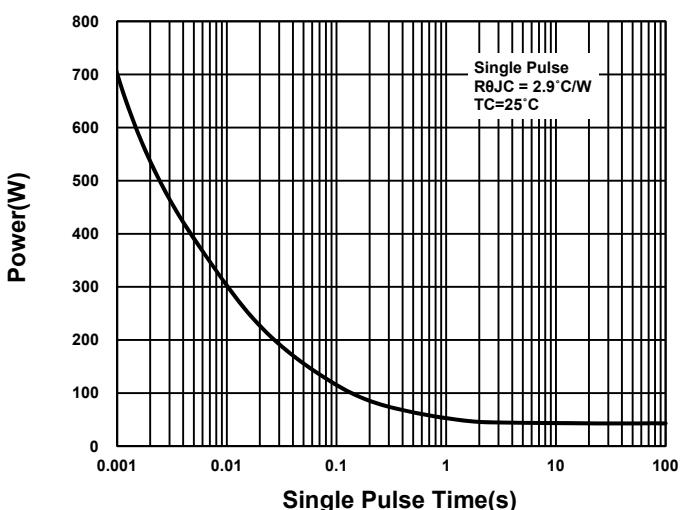


#### On-Resistance VS Gate-To-Source



#### On-Resistance VS Drain Current



**NIKO-SEM****N-Channel High Voltage Mode  
Field Effect Transistor****P1560ZTF:TO-220F  
P1560ZTFS:TO-220FS  
Halogen-Free & Lead-Free****On-Resistance VS Temperature****Source-Drain Diode Forward Voltage****Safe Operating Area****Single Pulse Maximum Power Dissipation****Transient Thermal Response Curve**